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(Not for submission under 37 CFR 1.99)	Art Unit		2815	
	Examiner Name	Josep	h H. Nguyen	
	Attorney Docket Number		LUM-03-06-06	

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Application Number		10829141			
Filing Date		2004-04-21			
First Named Inventor Jame		es C. Kim			
Art Unit		2815			
Examiner Name	Josep	ph H. Nguyen			
Attorney Docket Number		LUM-03-06-06			

/JN/ ARPAN CHAKRABORTY et al., "Nonpolar InGaN/GaN emitters on reduced-defect lateral epitaxially overgrown aplane GaN with drive-current-independent electroluminescence emission peak," Applied Physics Letters, Vol. 85, No. 22, 29 November 2004, pp. 5143-5145.							
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